



2829.

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Akihiko EBINA et al.

Group Art Unit: 2829 .

Application No.: 10/052,255

Examiner: S. Geyer

Filed: January 23, 2002

Docket No.: 111778

For: METHOD OF MANUFACTURING SEMICONDUCTOR INTEGRATED CIRCUIT
DEVICE INCLUDING NONVOLATILE SEMICONDUCTOR MEMORY DEVICES

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

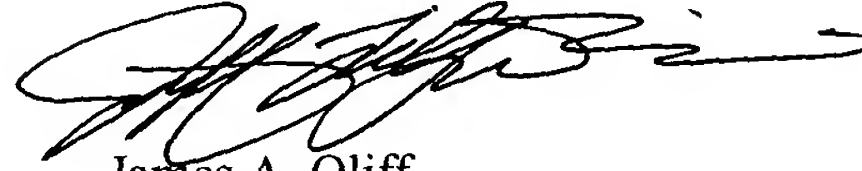
Sir:

Pursuant to 37 CFR §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. Unless otherwise indicated herein, one copy of each reference is attached. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

- ☒ 1. This Information Disclosure Statement is being filed (a) within three months of the U.S. filing date of this non-CPA application, OR (b) before the mailing date of a first Office Action on the merits in the present application. No certification or fee is required.
- ☒ 2. Each item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart application, and this communication was not received by any individual designated in §1.56(c) more than thirty days prior to the filing of this Information Disclosure Statement.

- ☒ 3. English-language Abstracts of the non-English language references are attached hereto.

Respectfully submitted,



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Date: July 29, 2003

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| <p>DEPOSIT ACCOUNT USE AUTHORIZATION Please grant any extension necessary for entry; Charge any fee due to our Deposit Account No. 15-0461</p> |
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Sheet 1 of 1

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|---|--|--|------------|--------------------------------------|-------|-------------------------------|--|
| Form PTO-1449 (REV. 8-83) | | US Dept. of Commerce PATENT & TRADEMARK OFFICE | | ATTY DOCKET NO. 111778 | | APPLICATION NO. 10/052,255 | |
| INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary) | | | | APPLICANT(S) Akihiko EBINA et al. | | | |
| | | | | FILING DATE January 23, 2002 | | GROUP 2829 | |
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| EXAMINER | | | | DATE CONSIDERED | | | |
| Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. | | | | | | | |

Date: July 29, 2003